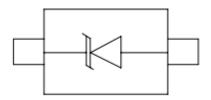


Description

The JS15U1GS30-2 is an uni-directional high power TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The JS15U1GS30-2 complies with the IEC 61000-4-2 (ESD) with $\pm 30 \mathrm{kV}$ air and $\pm 30 \mathrm{kV}$ contact discharge. It is assembled into an ultra-small lead-free SOD-323 package. The small size and high ESD surge protection make JS15U1GS30-2 an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

Circuit Diagram



Circuit and Pin Schematic

Marking Diagram



Transparent top view

57D:Device Marking Code

Features

- * 2000W peak pulse power (8/20µs)
- * Low leakage:uA level
- * Operating voltage: 15V
- * Low clamping voltage
- * One power line protects
- * Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test

Air discharge: ±30kV

Contact discharge: ±30kV

- IEC61000-4-5 (Lightning) 60A (8/20μs)
- * RoHS Compliant
- * Package: SOD-323

Applications

- * Mobile Phones and Accessories
- * Hand Held Portable Applications
- * Battery Protection
- Power Supply Protection
- * Peripherals

Ordering Information

Part Number	Packaging	Reel Size	
JS15U1GS30-2	3000/Tape & Reel	7 inch	



Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

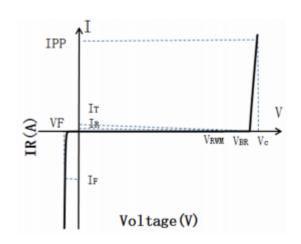
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	2000	W
Peak Pulse Current (8/20μs)	IPP	60	A
ESD per IEC 61000-4-2 (Air)	VESD	±30	kV
ESD per IEC 61000-4-2 (Contact)	VESD	±30	K V
Operating Temperature Range	TJ	-55to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C

Electrical Characteristics (T_A=25°C unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Reverse Working Voltage	Vrwm				15	V
Breakdown Voltage	VBR	$I_T = 1 \text{mA}$	16.5			V
Reverse Leakage Current	I_R	$V_{RWM} = 15V$			1	uA
Clamping Voltage	Vc	I _{PP} = 20A (8 x 20μs pulse)			20	V
Clamping Voltage	Vc	$I_{PP} = 60A (8 \times 20 \mu s \text{ pulse})$			33	V
Junction Capacitance	CJ	VR = 0V, $f = 1MHz$			450	pF

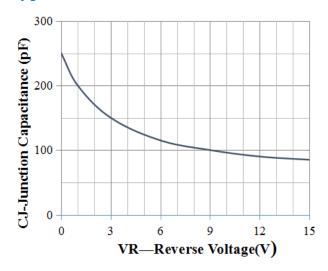
Portion Electronics Parameter

Symbol	Parameter	
Iτ	Test Current	
Ірр	Maximum Reverse Peak Pulse Current	
Vc	Clamping Voltage @Ic	

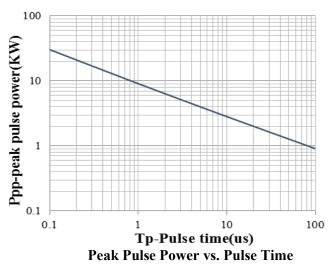




Typical Performance Characteristics (T_A=25°C unless otherwise Specified)

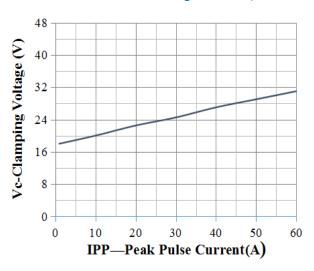


Junction Capacitance vs. Reverse Voltage

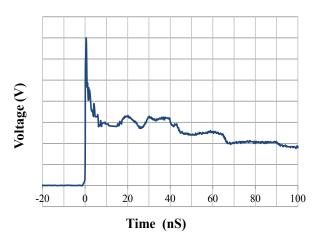


120 100 80 80 40 20 0 0 25 50 75 100 125 150 Ambient Temperature_Ta(°C)

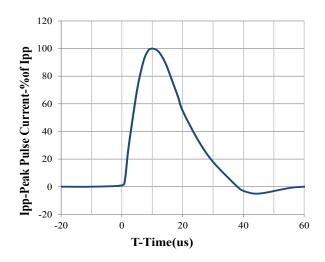
Power Derating Curve



Clamping Voltage vs. Peak Pulse Current



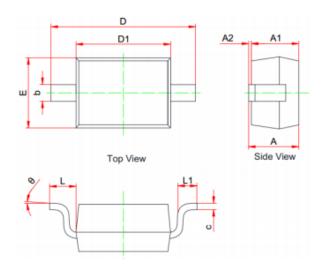
IEC61000-4-2 Pulse Waveform



8 X 20us Pulse Waveform

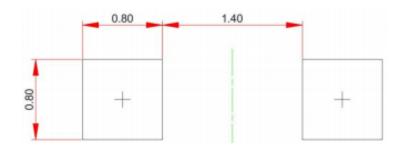


SOD-323 Package Outline Drawing (Dimensions in millimeters)



	MILLIMETERS		
SYM	MIN	NOM	MAX
Α	0.800		1.100
A1	0.800		0.900
A2	0.000		0.100
b	0.250		0.400
С	0.080		0.177
D1	1.600	1.700	1.800
D	2.300		2.800
E	1.150		1.400
L		0.475REF	
L1	0.100		0.500
Θ	0°		8°

Suggested Land Pattern



Unit: mm

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